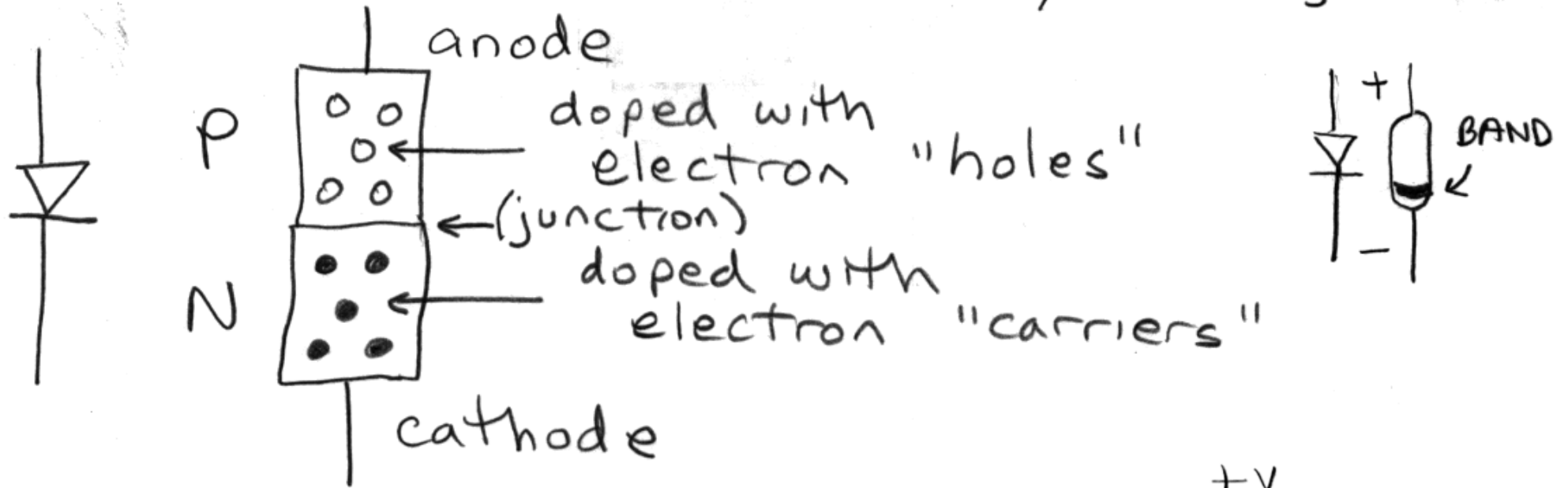


Non-Linear Circuits

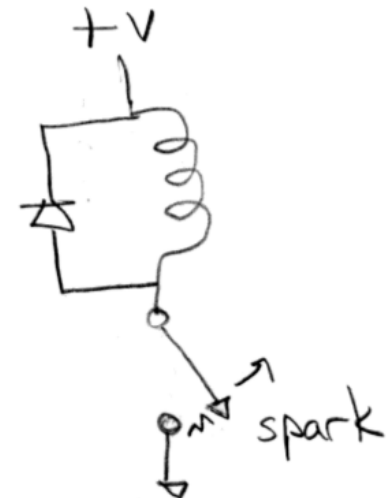
- We have been talking about linear circuits
 - DC represented by Linear equations
 - AC represented by Linear *differential* equations
- Now we introduce non-linear circuits
 - Mathematical representation more complex
 - We describe their behavior in other ways
 - Simplifying assumptions actually make it easier sometimes than linear circuits
 - New capabilities can include *gain* (amplification)

Diode

Solid state diodes have two types of material: P = positive, N = negative



we've seen the diode once already, shorting out the surge in a coil.

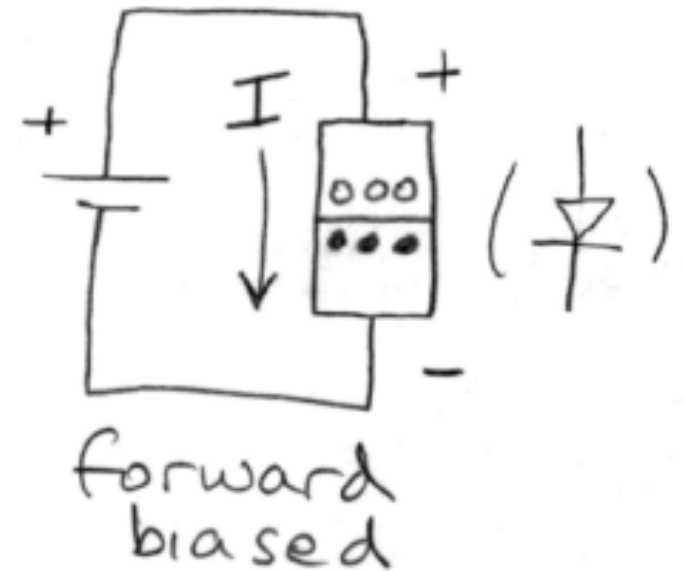


Little piece of the period Table

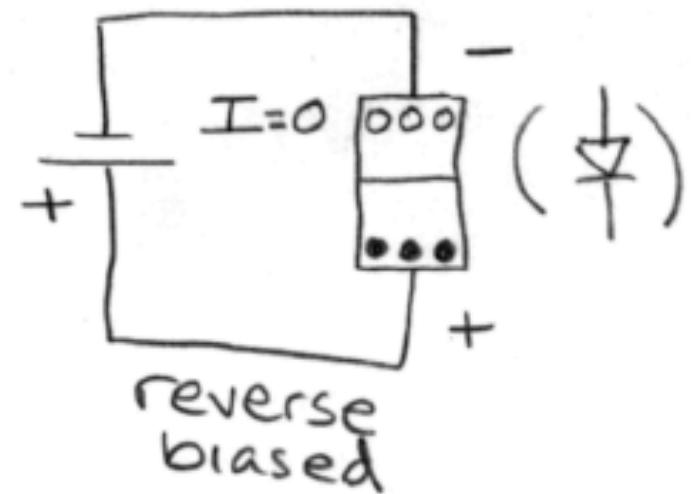
	hole (missing electron)	semiconductor (covalent)	carrier (extra electron)	
	5 B	6 C	7 N	
	13 Al	14 Si	15 P	most commercial solid-state devices
	31 Ga	32 Ge	33 As	some more exotic devices
Valance group	3	4	5	

Diode acts as a one-way valve

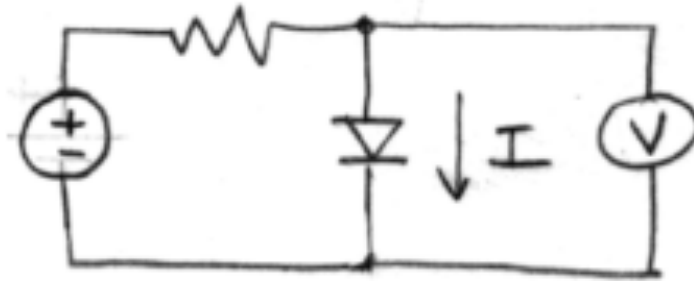
when "forward biased"
holes touch carriers
at the junction and
current flows,



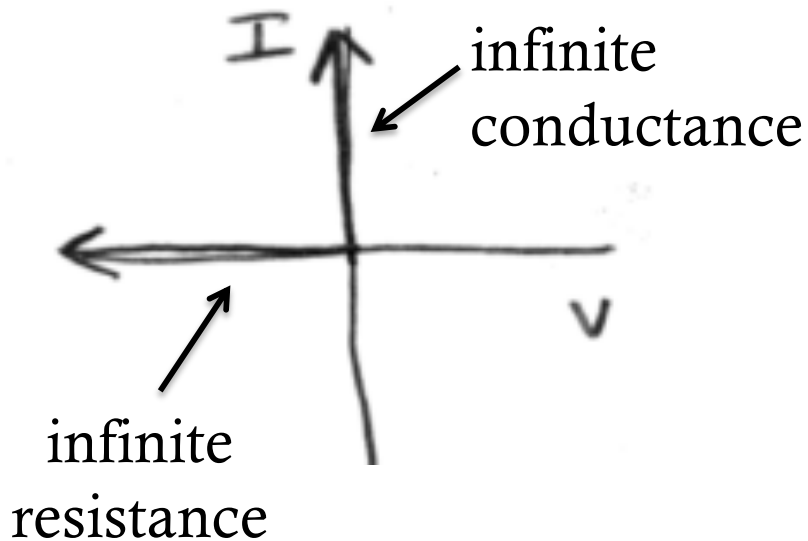
when "reverse biased"
holes do not touch carriers
and current does not flow,



Graphical Representation on V - I Plane



Ideal Diode

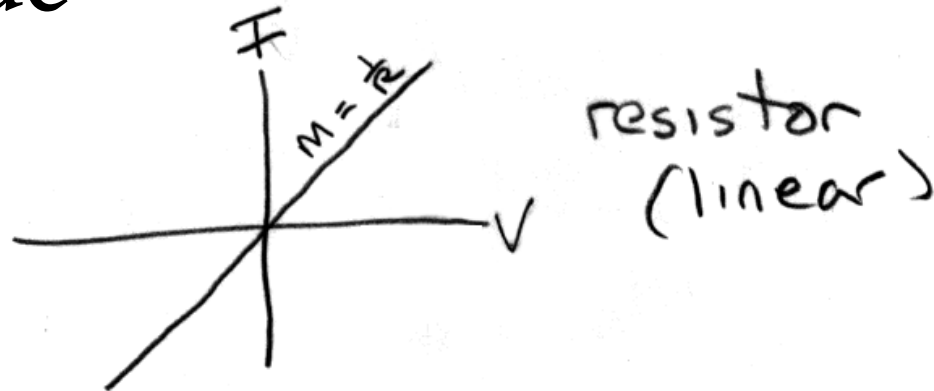


Real Diode

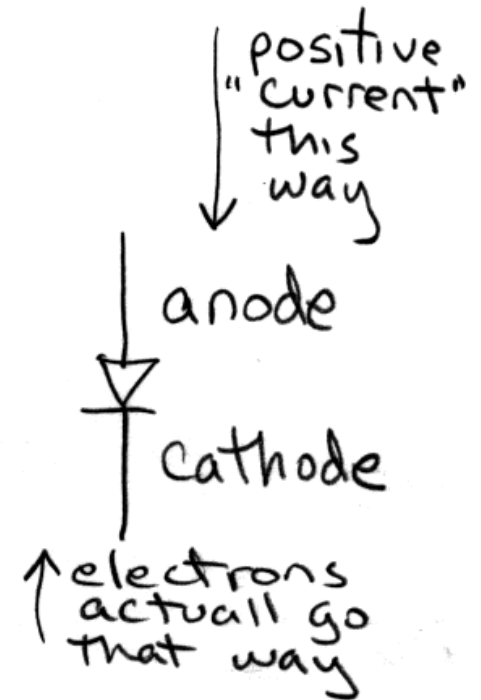
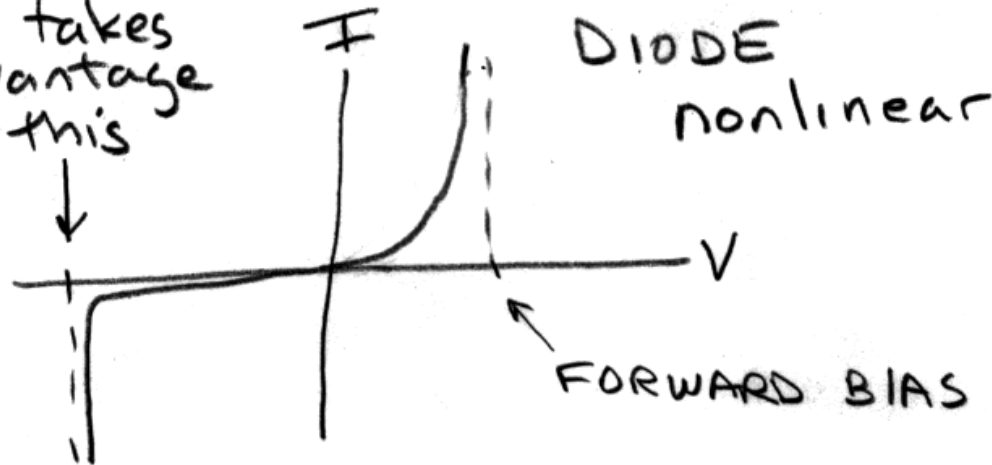


- Forward biased current is exponentially related to voltage, asymptotes to 0.5-0.7 V for silicon, $\sim 0.2V$ for germanium.
- Reverse biased current is zero until "reverse breakdown" voltage.


Zener Diode




Zener takes advantage of this



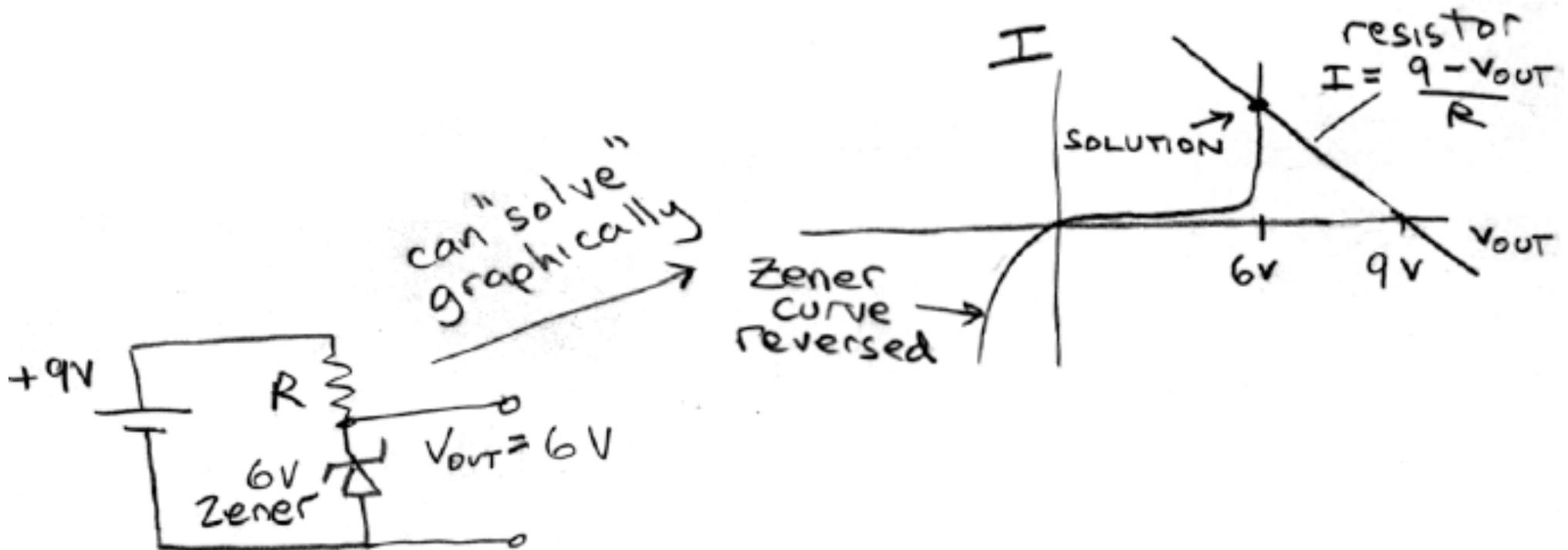
REVERSE BREAKDOWN VOLTAGE

VERY HIGH  regular diode
eg. 1N914

specified useful voltage  zener diode

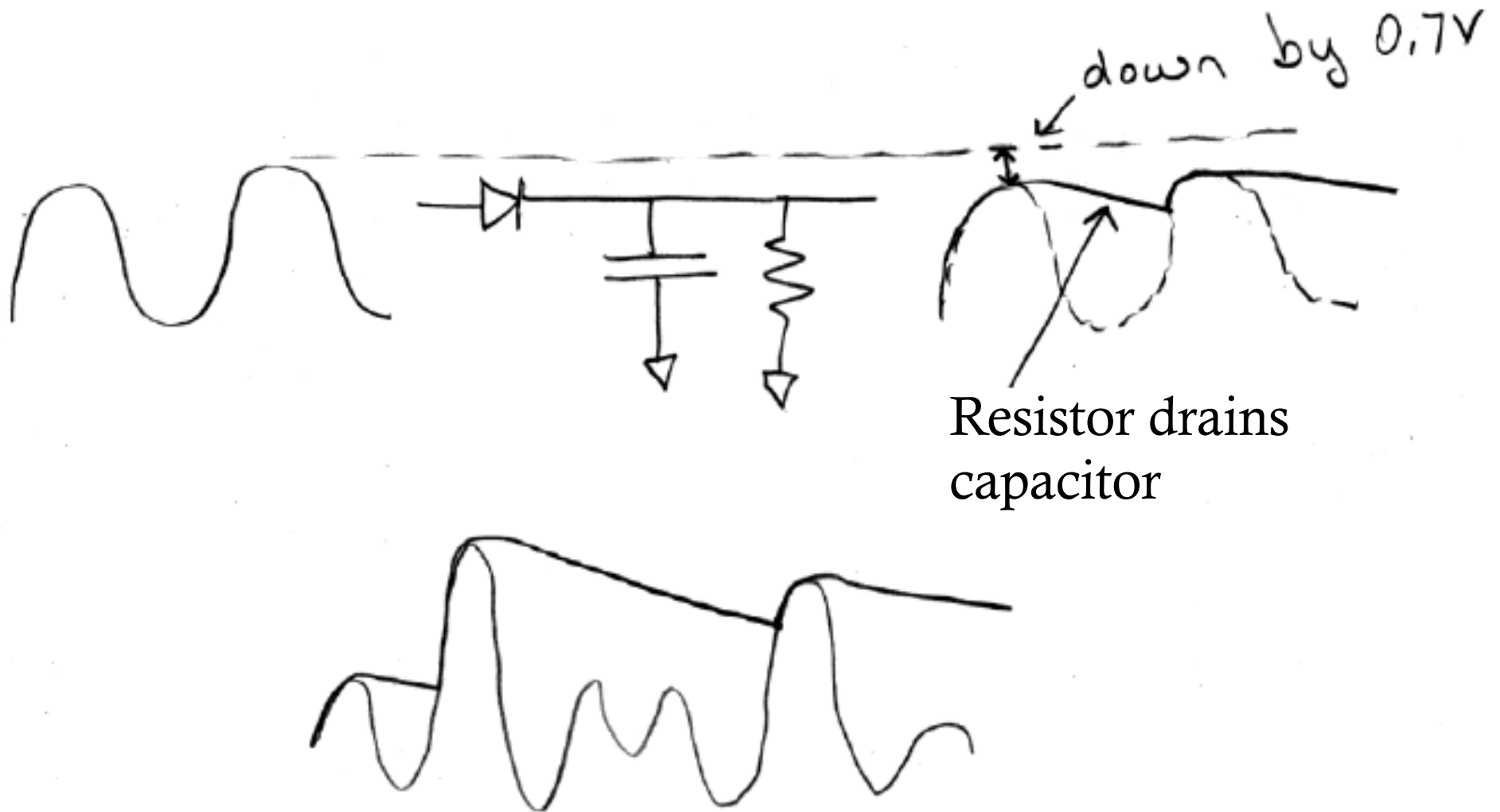
Zener worked at CMU

Can solve circuits graphically on V - I graph



- Zener points *into* the current and is purposefully *biased* in the reverse breakdown region.
- Like pressure regulator on a SCUBA tank.

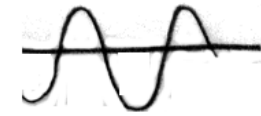
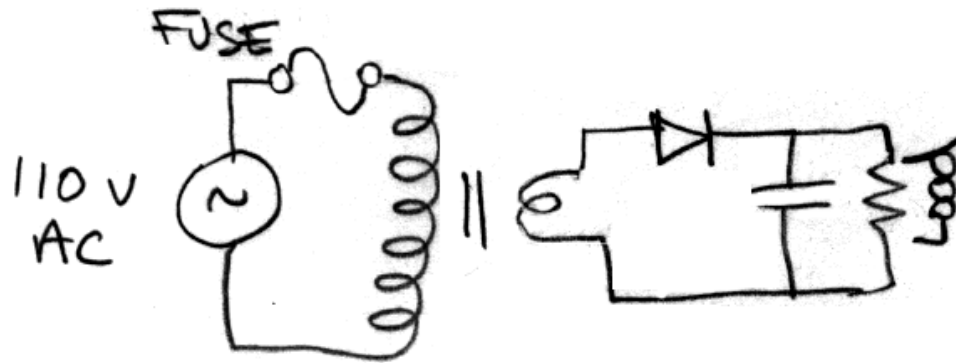
Diode as *Peak Detector*



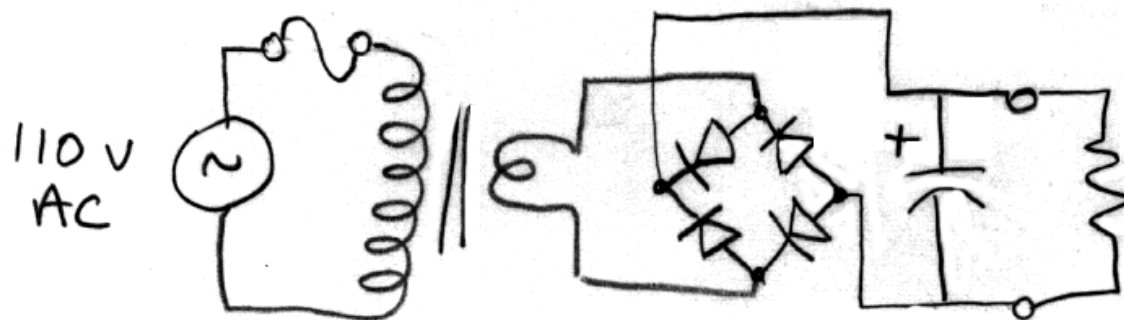
- Keeps a running maximum (down by diode drop)
- Resistor “resets” peak detector with time constant RC
 - Otherwise it gives highest voltage since beginning of time

Rectification

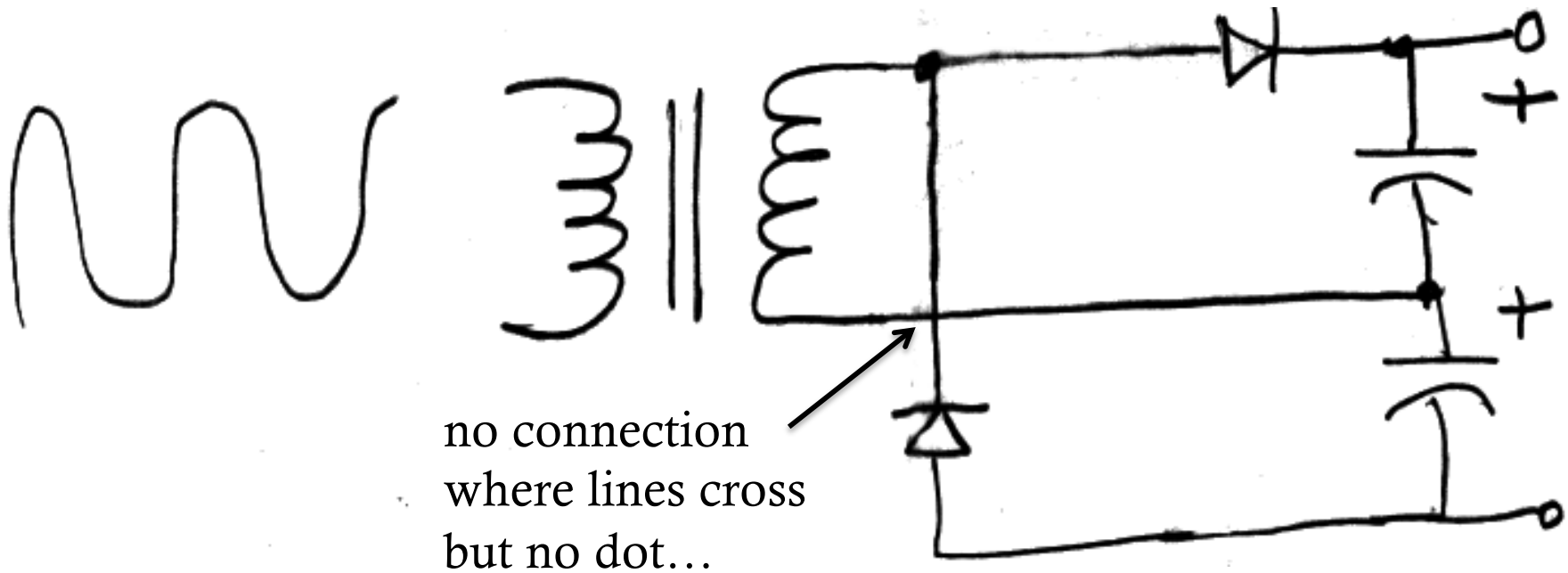
- Turns AC into DC
- Half-Wave Rectification



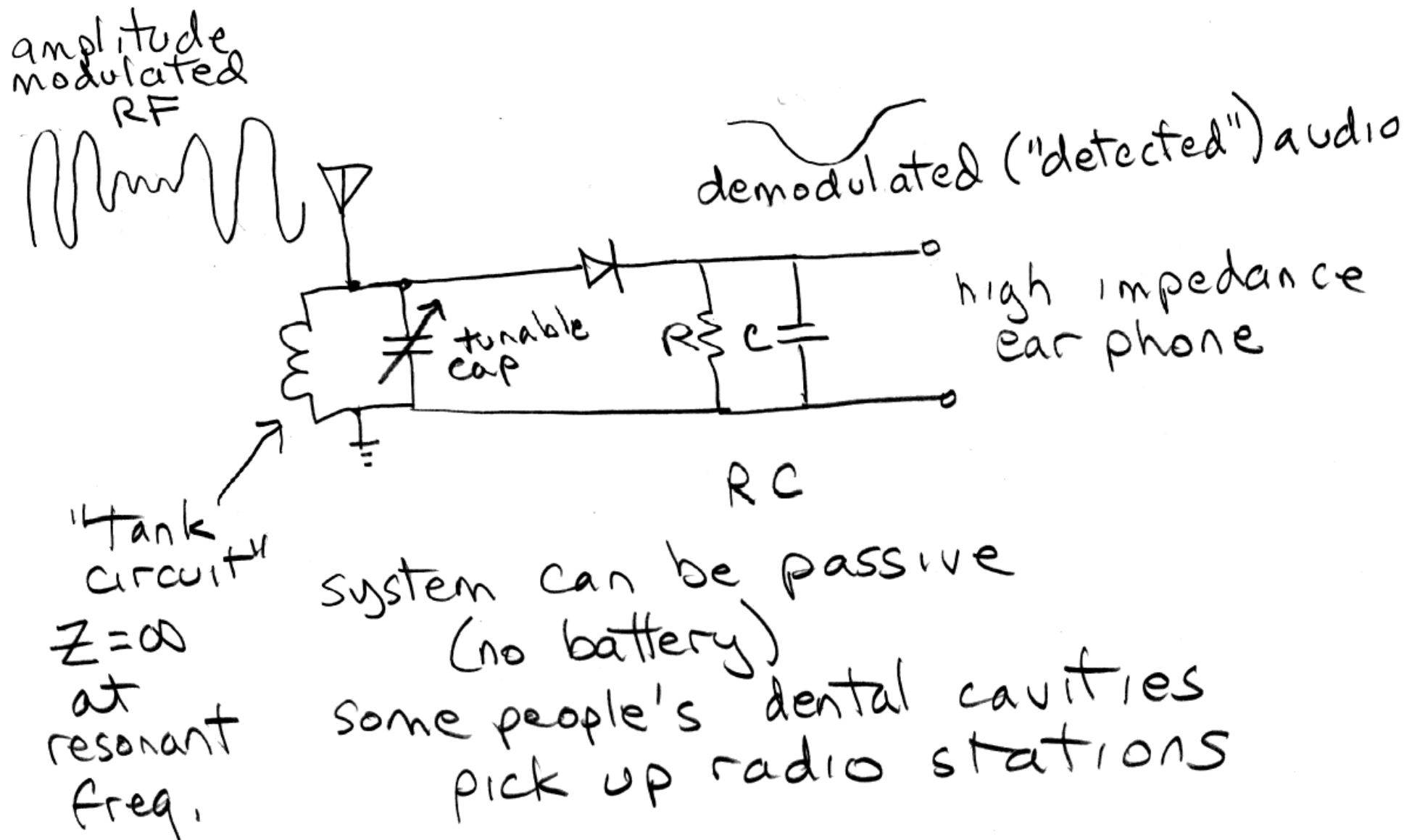
- Full-Wave Rectification



Voltage Doubler



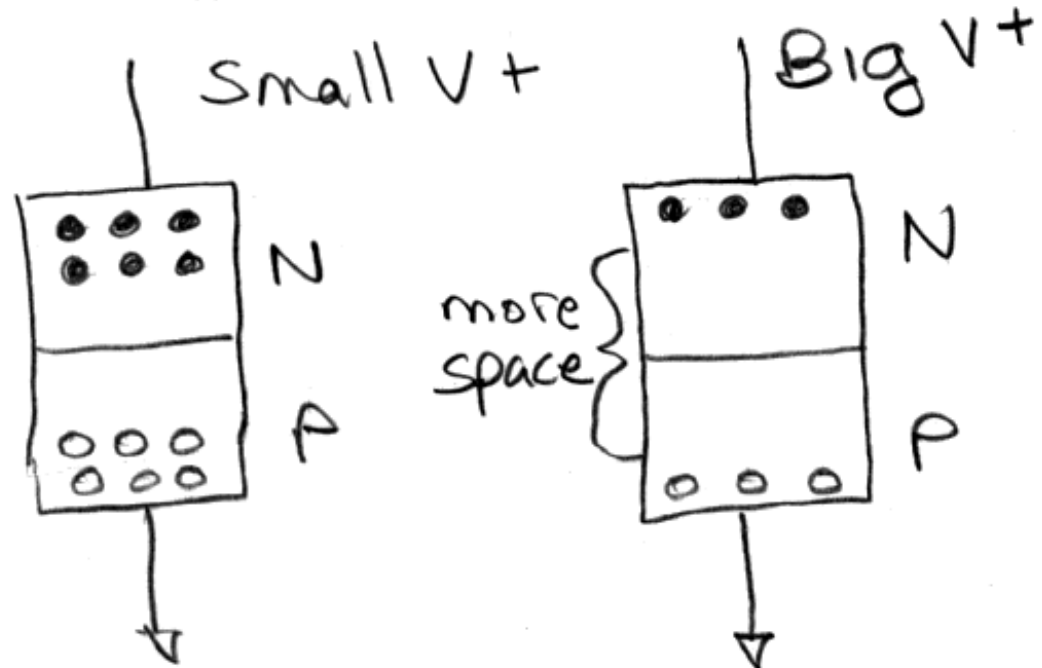
Amplitude Modulation (AM) radio receiver



Varactor (variable capacitor diode)



C increases with $V+$



used to modulate RF (radio freq.)
oscillators

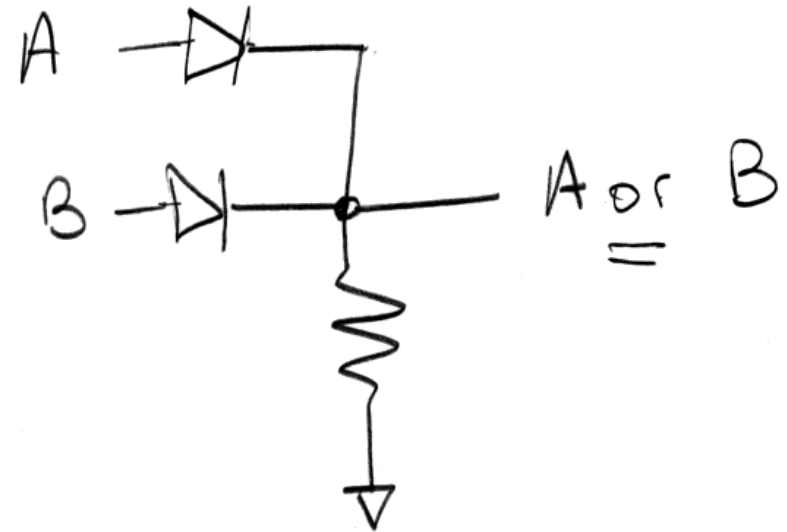
Logic with Diodes

Logic is non-linear
"Boolean"

A	B	A or B
0	0	0
0	1	1
1	0	1
1	1	1

1 means 5V

0 means 0V

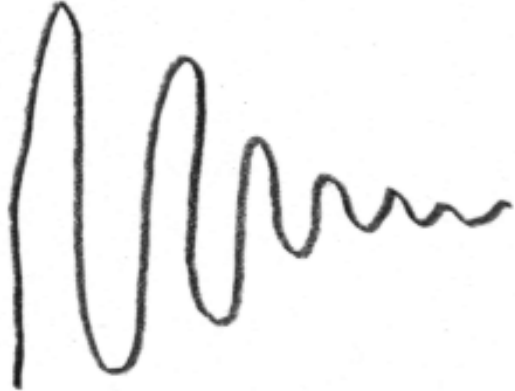


- When A is at 5V its diode is forward biased.
- If B is then at 0V, its diode is reverse biased, preventing it from bringing the output down.
- The inputs change each other's effect on the output, superposition does not apply, so the system is non-linear.

“Fuzz Box” guitar effect

- Non-linear system, clips voltage to diode forward voltage.
- Produces distortion / sustain

Guitar “plink”

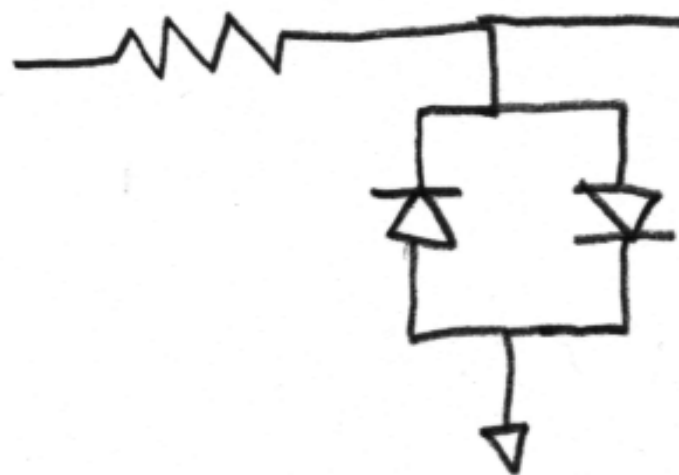


$V_{in}(t)$

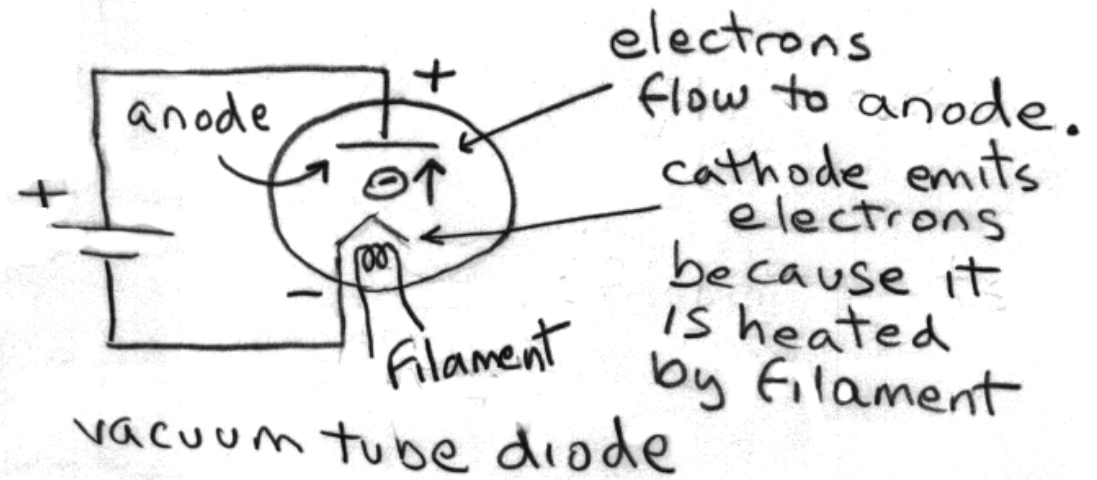
Guitar richly singing



$V_{out}(t)$



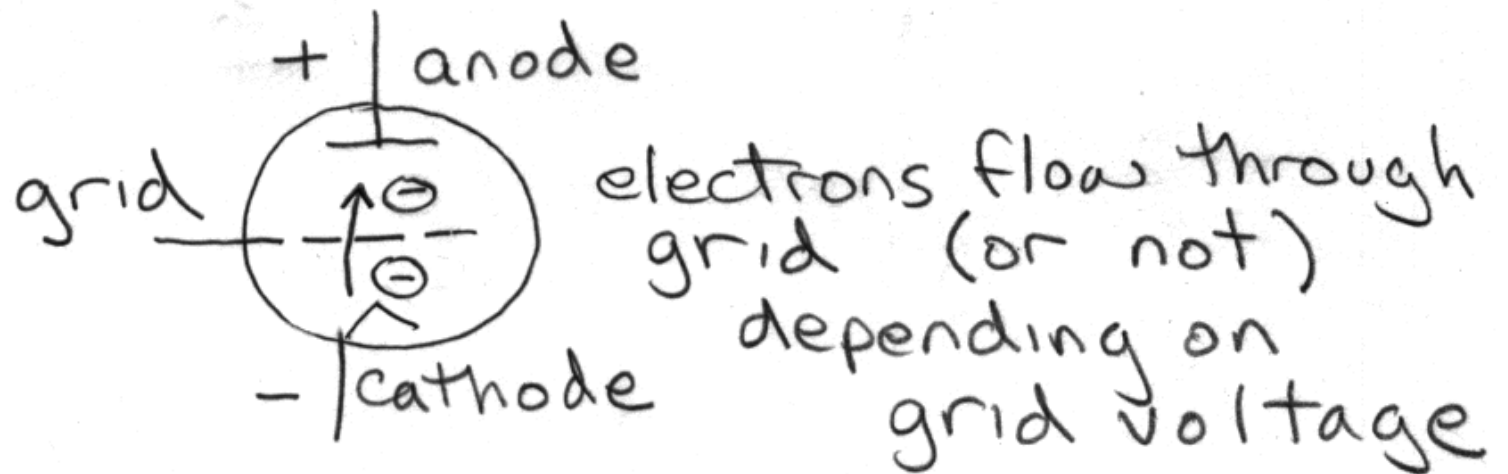
Before solid state there were vacuum tube diodes.



Edison's light bulb
led to the first diode vacuum tube,
current running only from
cathode to anode

Triodes - Amplification

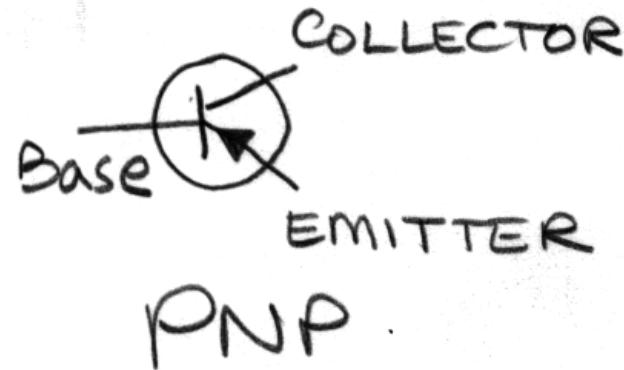
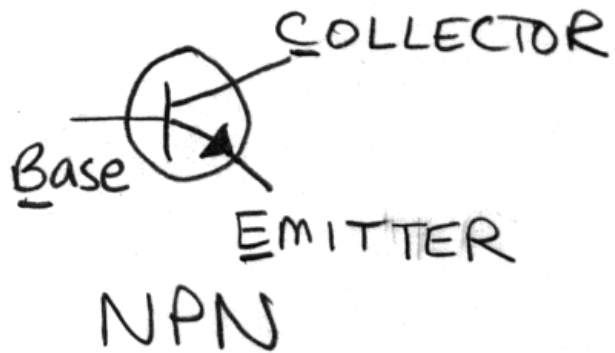
The addition of a "grid" allowed control of the flow of electrons from cathode to anode.



Introduced in 1920's. British called them "valves."

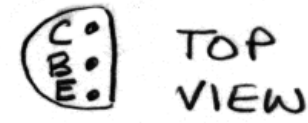
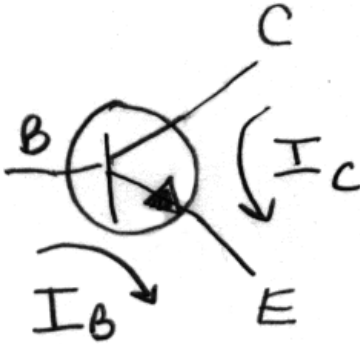
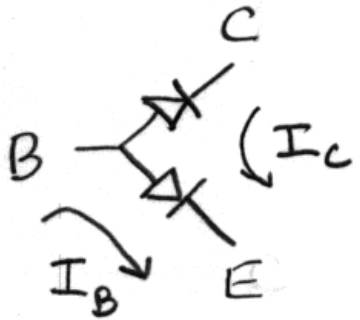
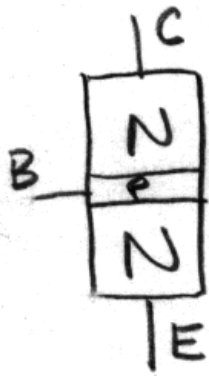
Transistor add a third layer, equivalent to the grid in the vacuum tube, called the "base"

Two kind, NPN and PNP

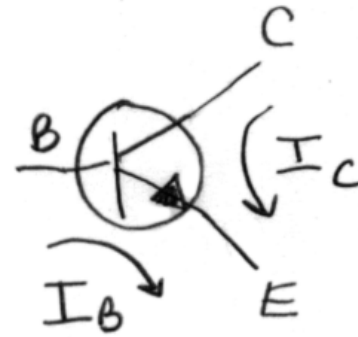
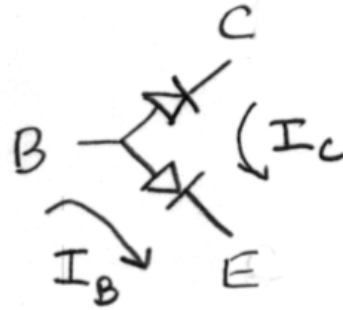
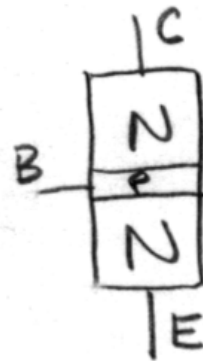


WE WILL USE ONLY NPN

2N3904



These are *Bipolar* Transistors (vs. *Field Effect* Transistors, which we'll see later). 191



FORWARD BIASING THE "DIODE" IN THE BASE-EMITTER JUNCTION FILLS THE HOLES IN THE THIN P LAYER AND ALLOWS THE REVERSE-BIASED COLLECTOR-BASE "DIODE" TO CONDUCT

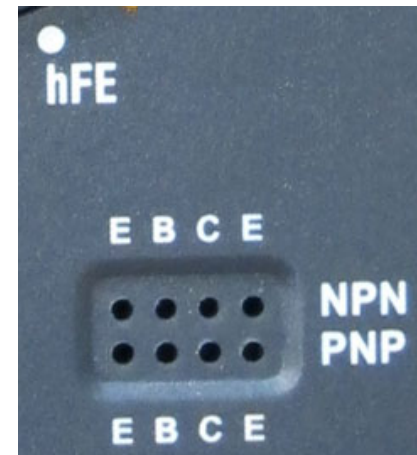
I_B = BASE CURRENT

I_C = COLLECTOR CURRENT

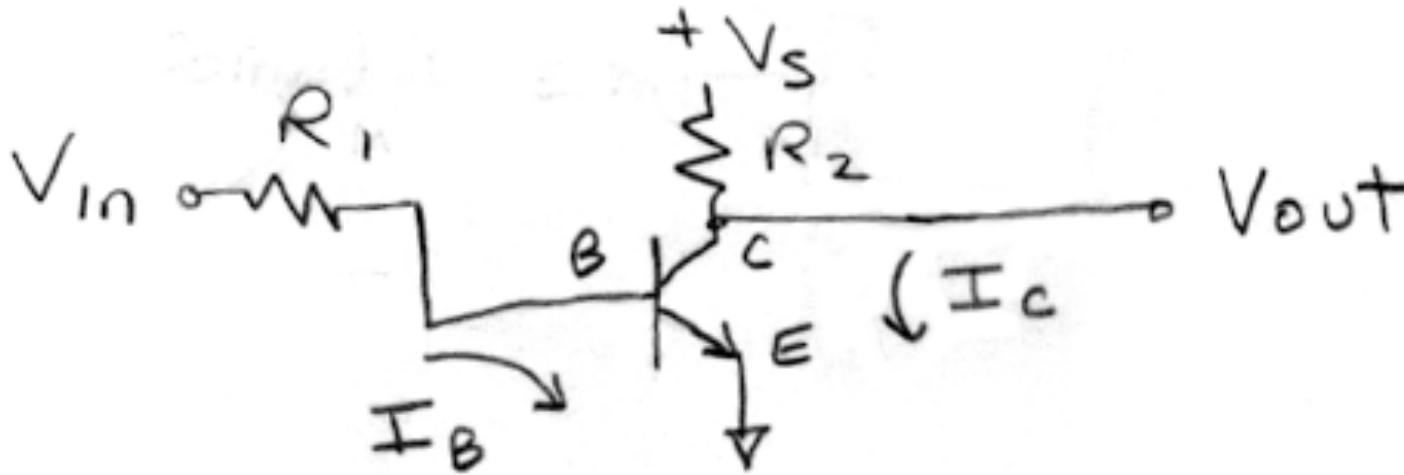
WHEN PROPERLY BIASED

$$I_C = \beta I_B$$

β is a constant
also known as h_{FE}



Transistor Circuits: *Common Emitter*

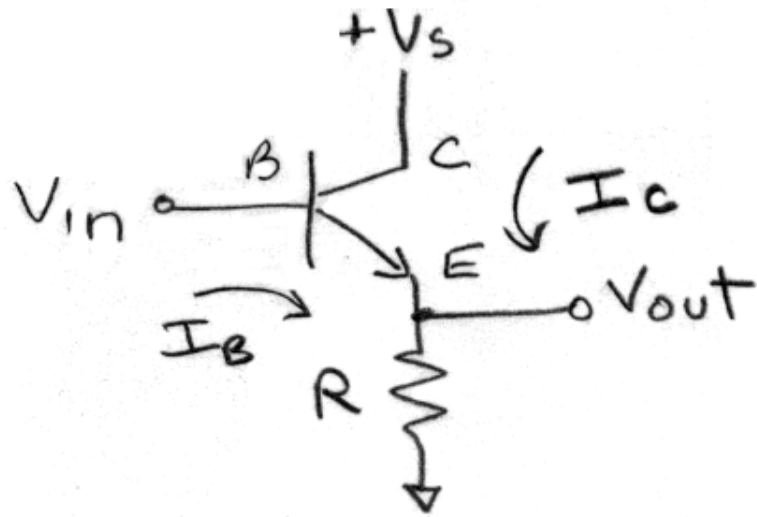


transistors often
drawn without
circle

Assuming 0.5 V base-emitter forward bias voltage drop

- $I_B = \frac{V_{in} - 0.5V}{R_1}$
- $I_C = \beta I_B = \beta \frac{V_{in} - 0.5V}{R_1}$
- $V_{out} = V_S - (V_{in} - 0.5V) \beta \frac{R_2}{R_1}$
- $\text{Gain} = \frac{\Delta V_{out}}{\Delta V_{in}} = -\beta \frac{R_2}{R_1}$

Transistor Circuits: *Emitter Follower*



assume the diode drop across the B-E junction is 0.5 V

$$V_{out} = V_{in} - 0.5\text{ V} \quad (\text{with } \underline{\text{current gain}})$$

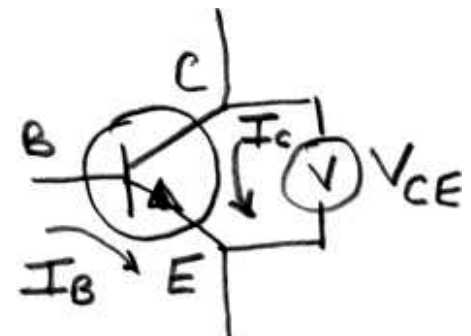
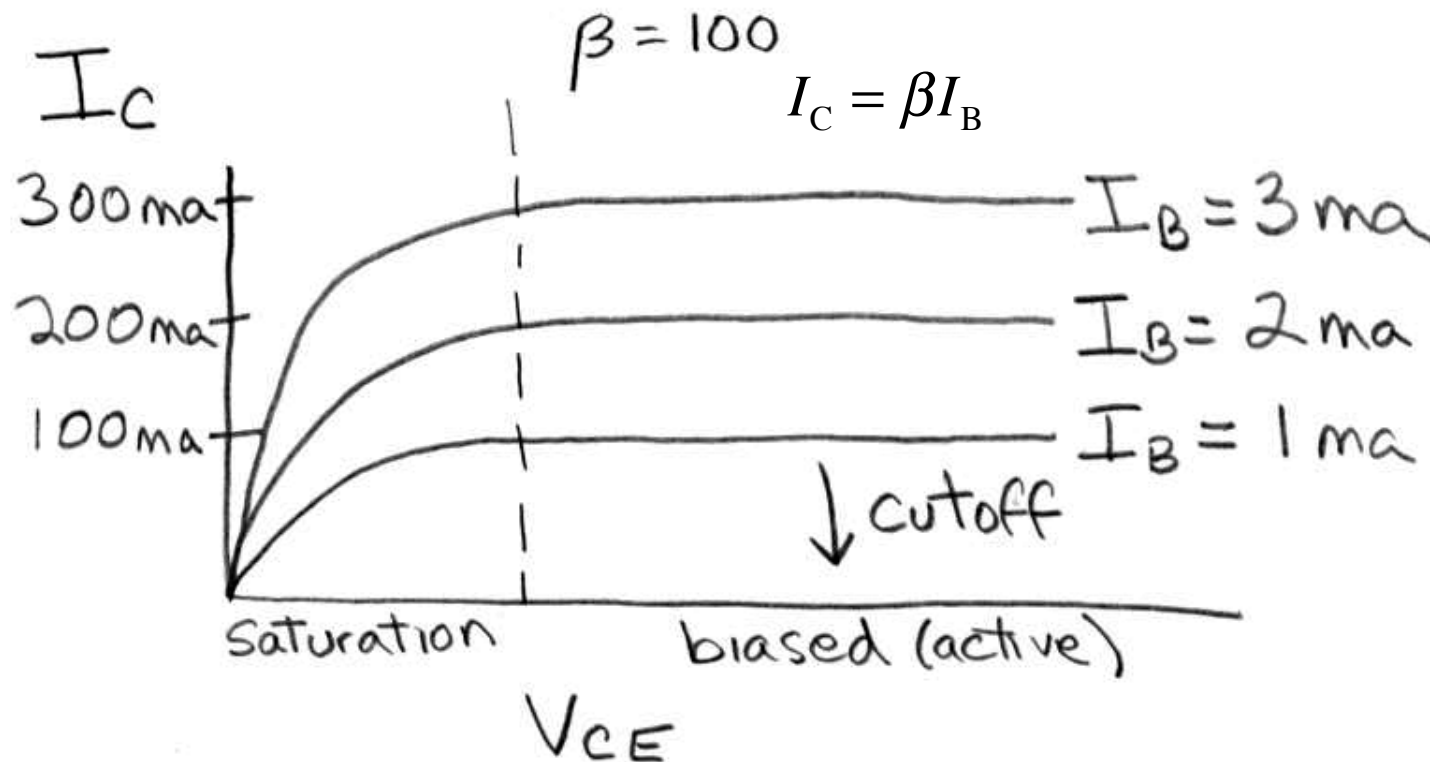
Very tight negative feedback

if V_{out} "too low" $\Rightarrow \uparrow I_B \Rightarrow \uparrow I_C \Rightarrow \uparrow V_{out}$

if V_{out} "too high" $\Rightarrow \downarrow I_B \Rightarrow \downarrow I_C \Rightarrow \downarrow V_{out}$

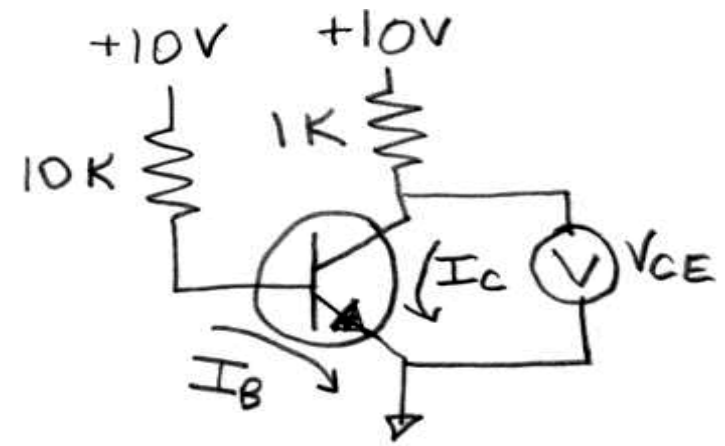
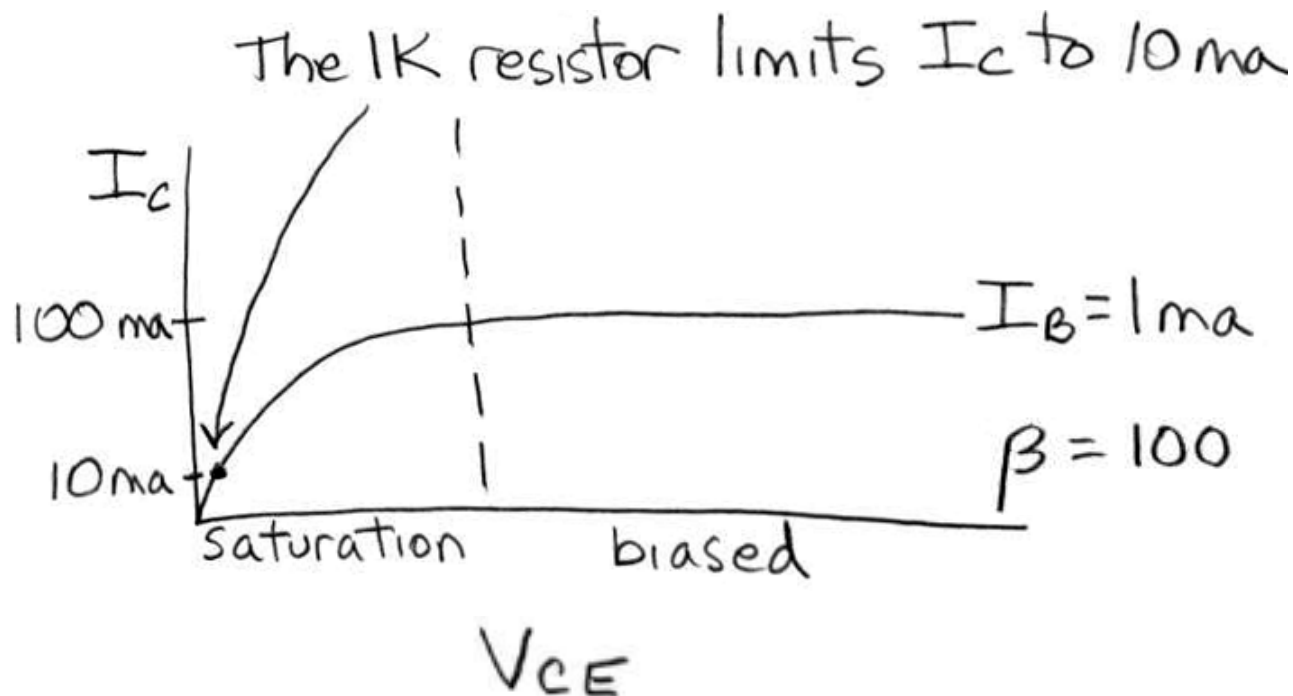
"just right" is $V_{out} = V_{in} - 0.5\text{ V}$

- Transistors operate in 1 of 3 regions:
 - Biased (active) : $I_C = \beta I_B$ independent of V_{CE} , where β is constant for a given transistor ($50 < \beta < 250$ for our 2N3904).
 - Cutoff : transistor is effectively turned off when I_B is too small.
 - Saturation : transistor is “wide open” with the current limited elsewhere in the circuit.

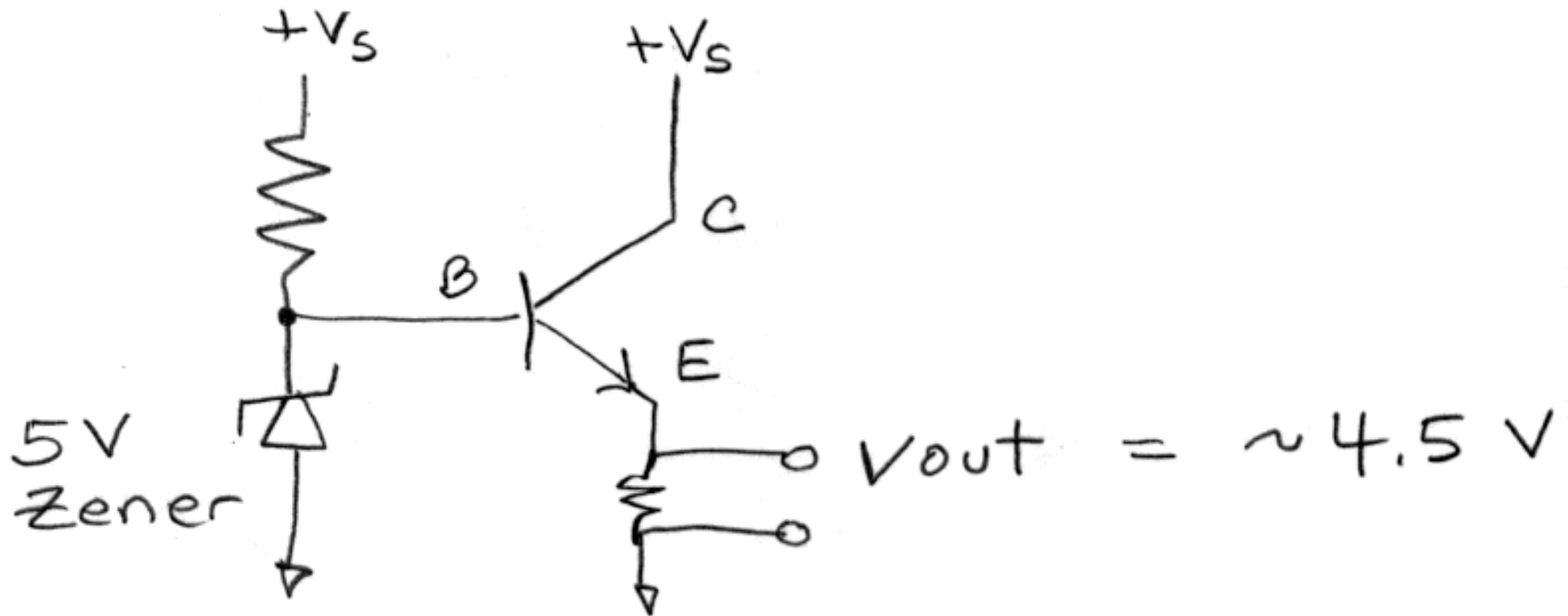


Transistor in the *saturated* region

- $I_B = 1 \text{ mA}$ so I_C should be 100 mA , making $V_{CE} = -90 \text{ V}$!
- Transistor is not a source of energy and can't do that.
- So transistor is wide open, with current limited elsewhere.
- V_{CE} settles below the “biased” region, in effect a short circuit doing the best it can.



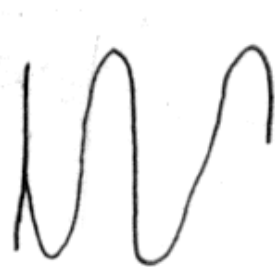
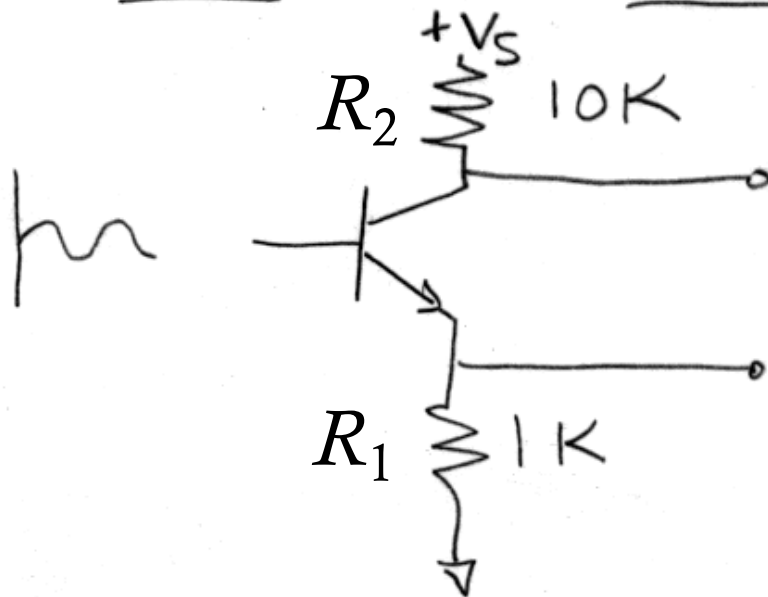
Example: Emitter Follower as “Buffered” Voltage Source



V_{out} acts more like a perfect voltage source because transistor supplies more current as needed

We would like to build amplifiers whose voltage gain only depends on linear components (resistors).

GETTING VOLTAGE GAIN β -independent



inverted signal
with 10x
voltage gain
independent of β

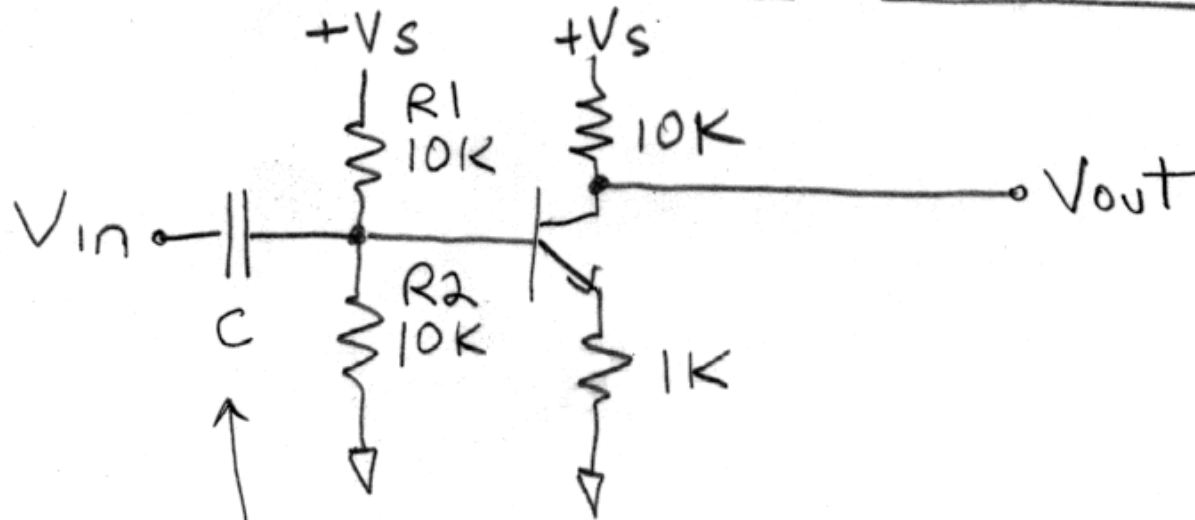


same voltage
but with
current gain

$$\text{Gain} = -\frac{R_2}{R_1}$$

Classic Audio Amplifier

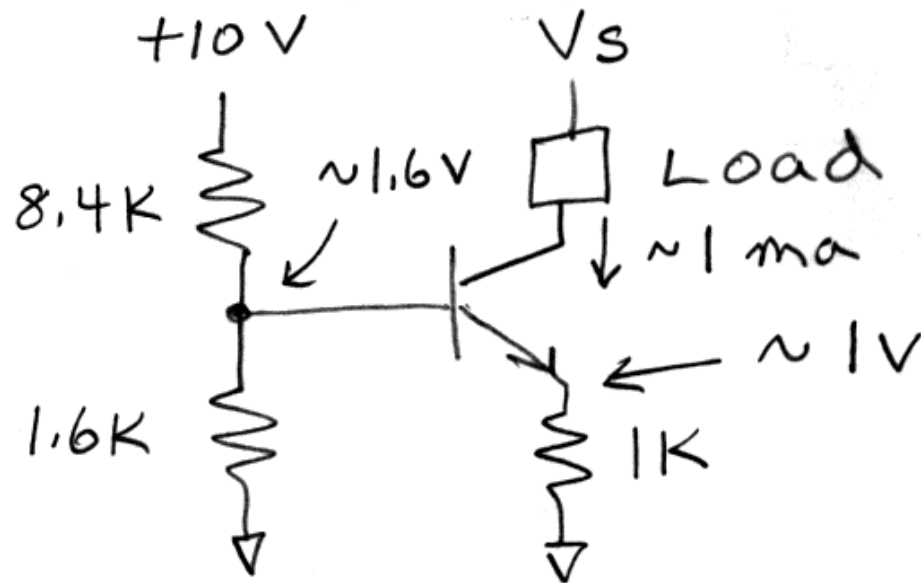
BIASING AND AC COUPLING



R_1 and R_2
"BIAS" THE
TRANSISTOR, I.E.
THEY PROVIDE
THE DC CURRENT
TO MAKE THE
TRANSISTOR OPERATE
IN ITS PROPER
RANGE

THE INPUT CAPACITOR REMOVES
THE DC PORTION OF V_{in} AND
ONLY PERMITS THE VARYING
PORTION OF V_{in} TO BE
AMPLIFIED (BY -10).

1 mA Current Source



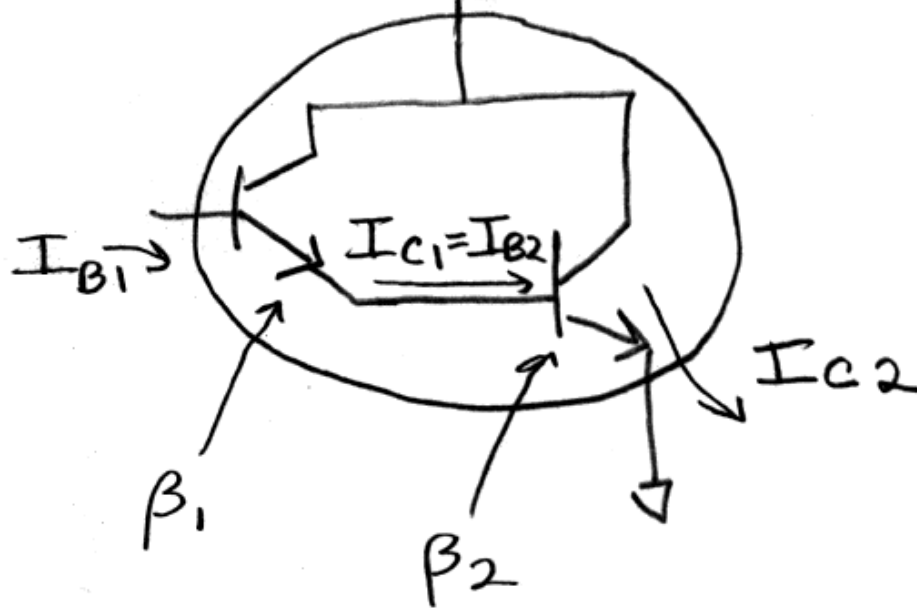
IRRESPECTIVE OF
 V_S AND THE
LOAD RESISTANCE
(WITHIN REASON)
1mA will be
drawn through
the load.

Assumes $V_{BE} = 0.6 \text{ V}$

Darlington Transistor (two transistors in one)

THE "DARLINGTON"

OR HOW TO GET REALLY BIG β



$$I_{C1} = \beta_1 I_{B1}$$

$$I_{C2} = \beta_2 I_{B2}$$

$$I_{C2} = \beta_1 \beta_2 I_{B1}$$

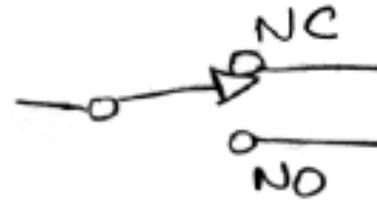
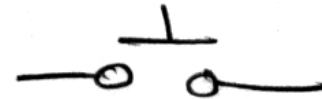
the effective β is the product of the two individual β 's

Gain

- Before transistors, our circuits (with resistors, capacitors, coils, and diodes) had just one stable equilibrium.
- Transistors add *gain*, the ability to control a large voltage or current with a smaller voltage or current.
- This leads to *bistable* and *unstable* circuits.
- We will demonstrate this next with *relays*, which are magnetically activated switches, and which therefore have gain.

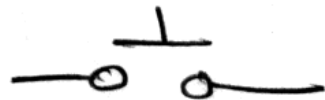
Switches and Relays

toggle vs. momentary

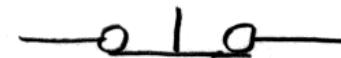


a spring
is
implied

Normally open vs.
(NO)



Normally closed
(NC)

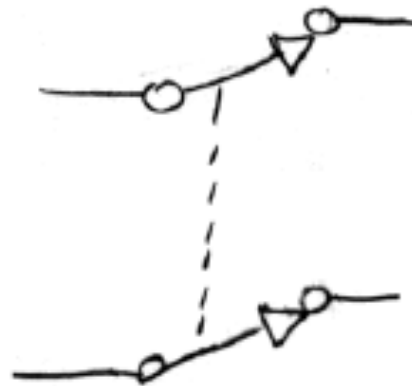


More Switches

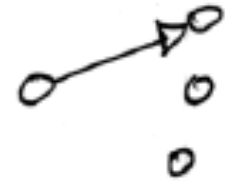
poles and throws



1P2T
"single pole-
double throw"



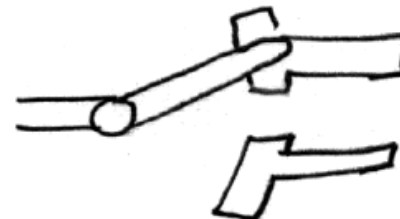
2P1T
"double pole-
single throw"



1P3T

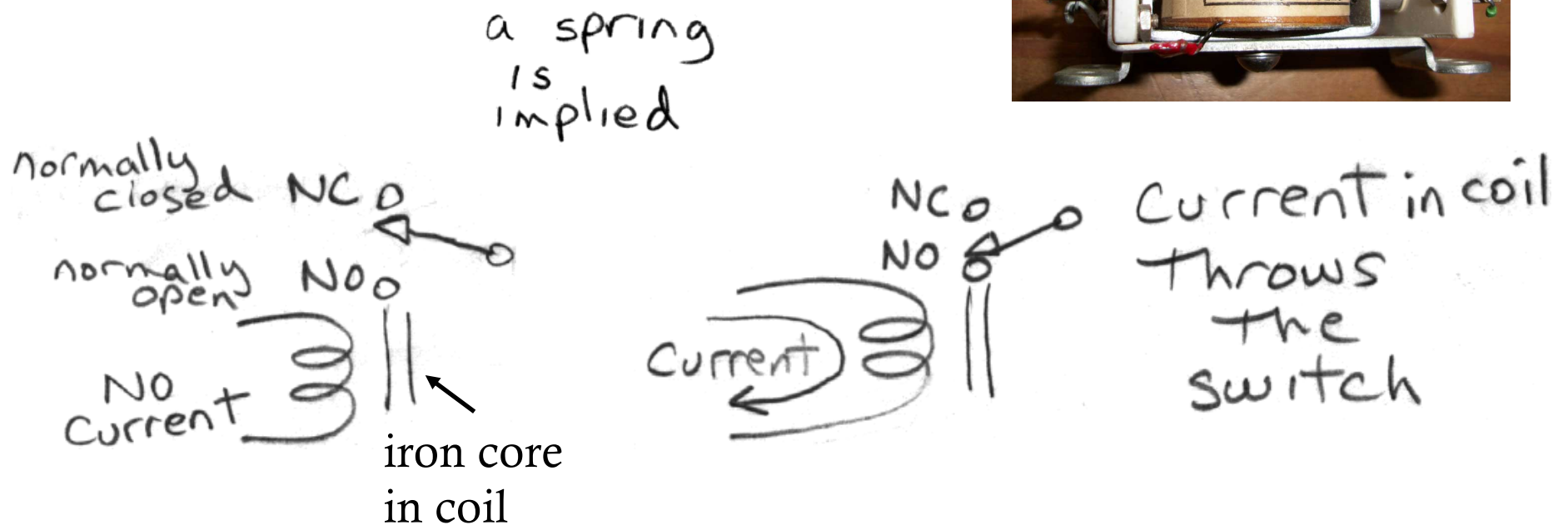


MAKE-BEFORE-BREAK



BREAK-BEFORE-MAKE

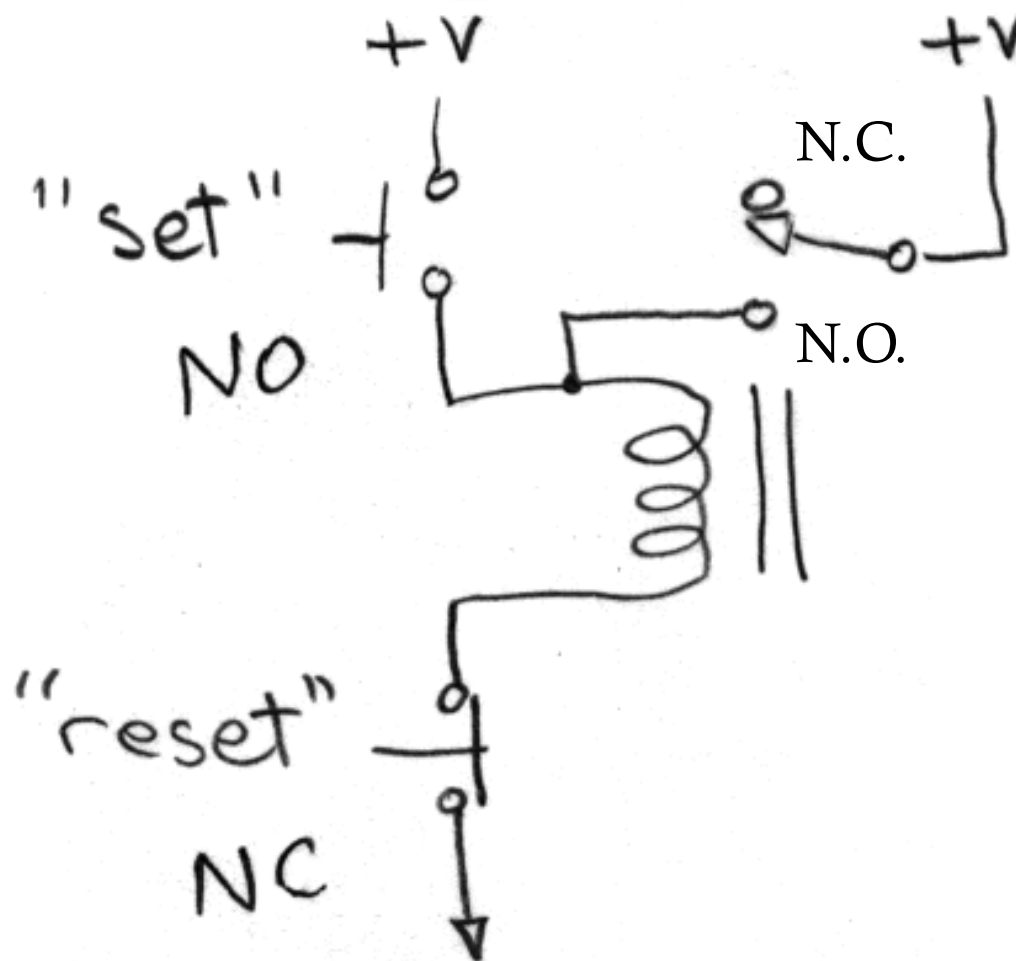
Relays



- Switch thrown by electromagnet pulling iron in the switch lever against a spring.
- Like transistors, relays introduce *gain*.
- Gain permits circuits that are either:
Bistable (with memory) or Unstable (that oscillate)

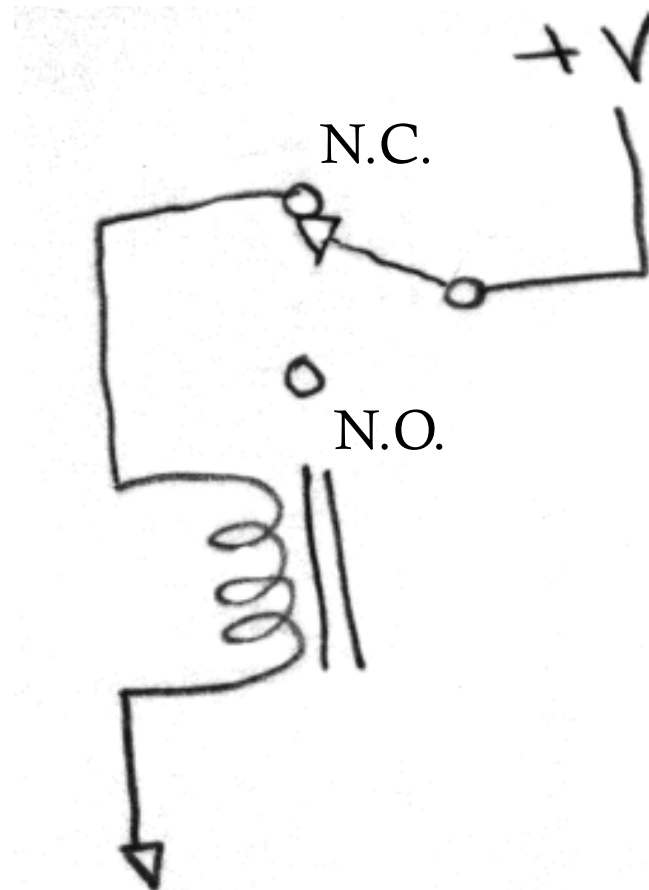
Bistable Relay Circuit

- the Latch
 - *Positive* feedback: reinforces its present state, whichever it is (memory)

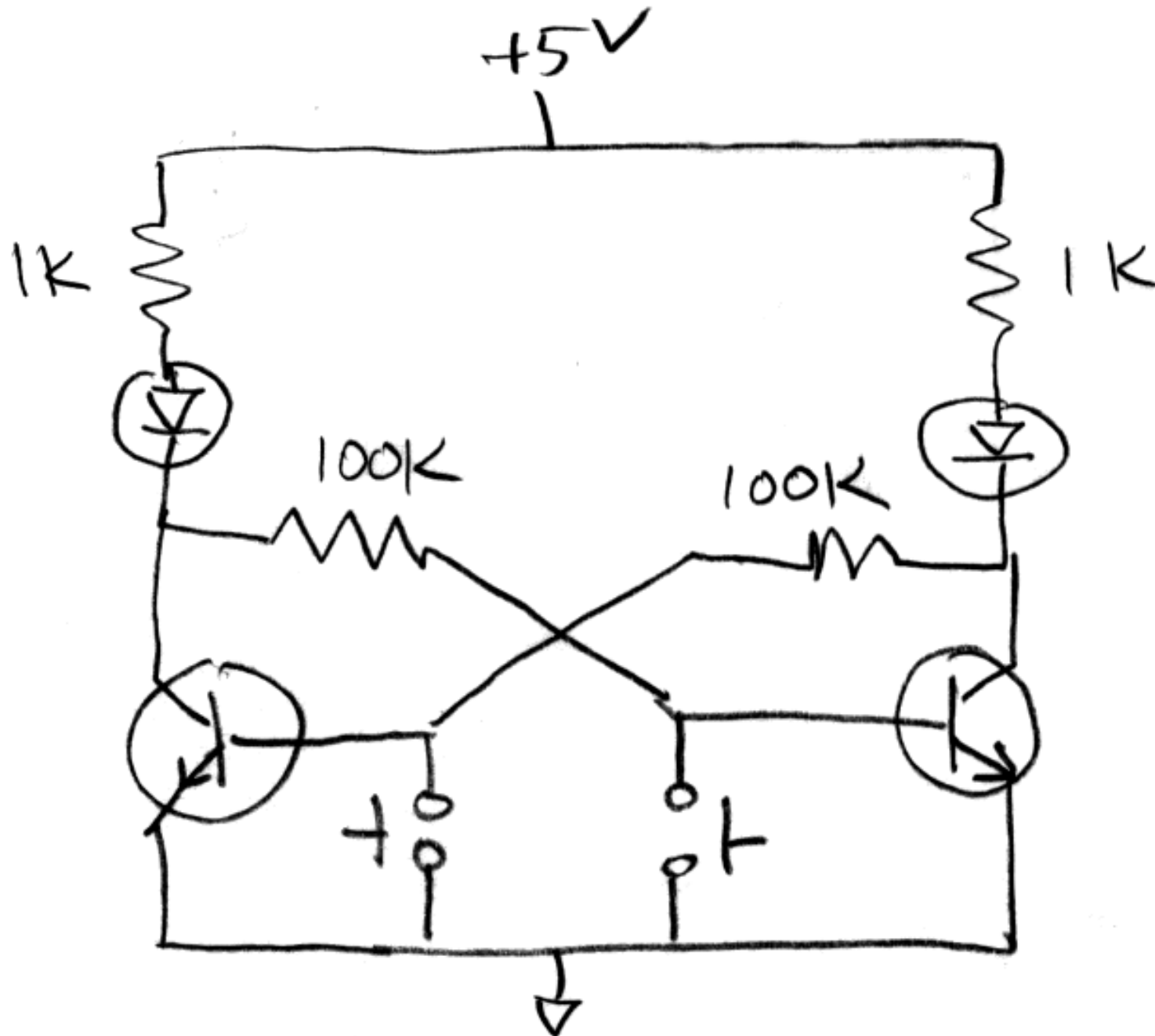


Unstable Relay Circuit

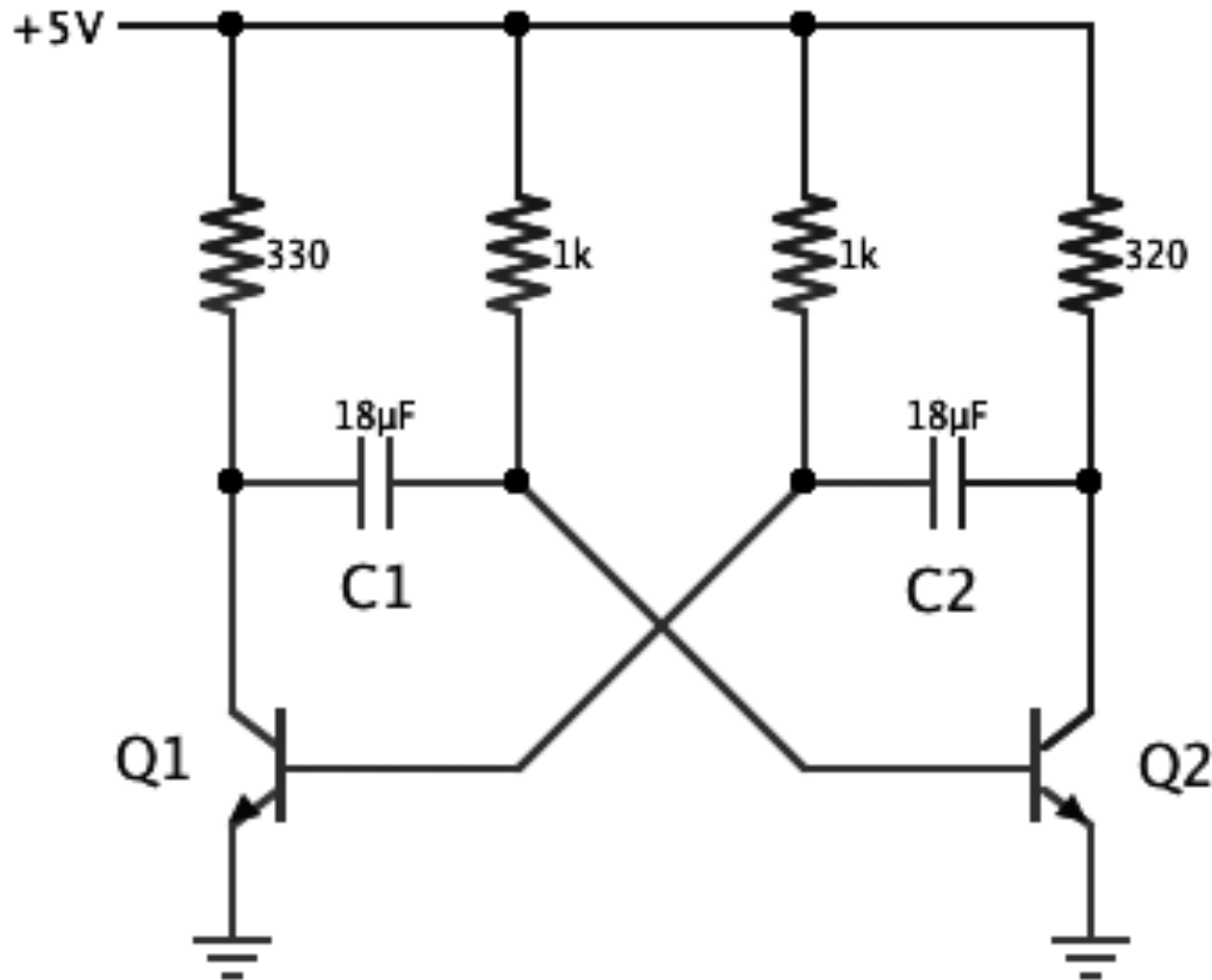
- the Buzzer
 - *Negative* feedback: disavows its present state, oscillates (although negative feedback can also converge to a single midpoint in some systems)



Bistable Transistor Circuit (Flip Flop)



Unstable Transistor Circuit (Multivibrator)

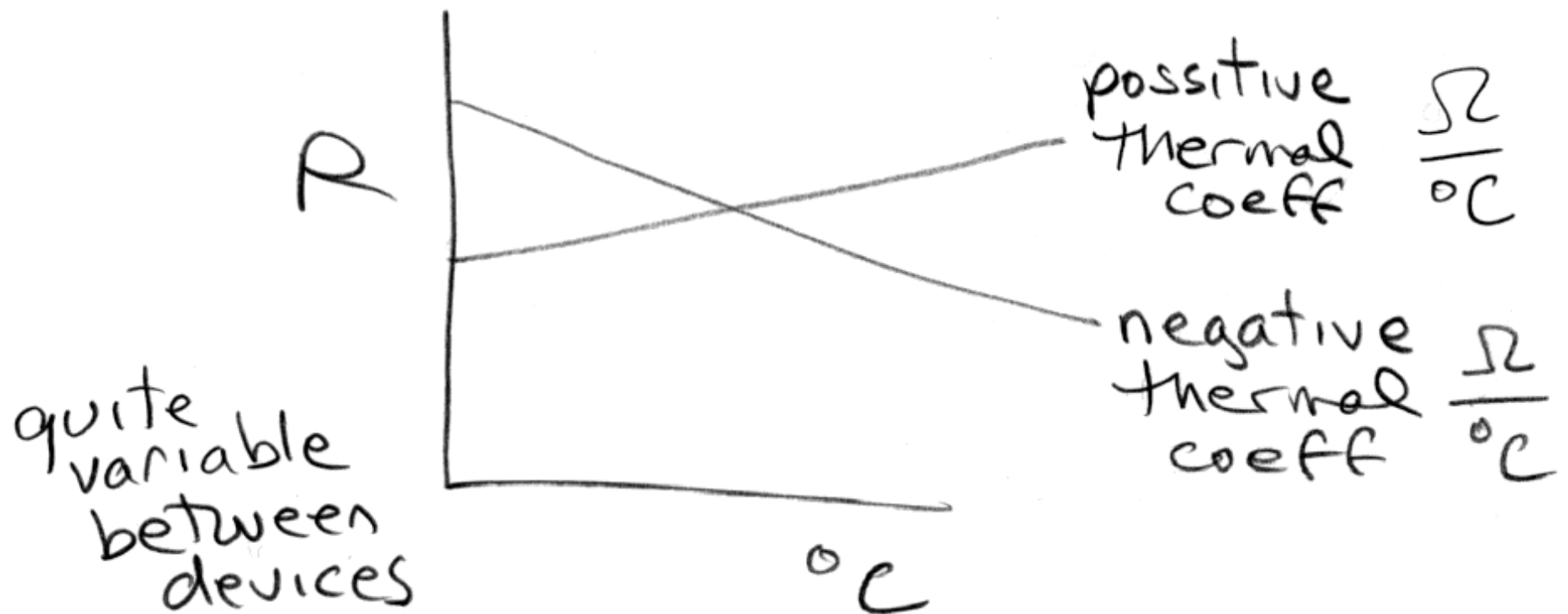


With Q1 on, C1 charges, until base of Q2 high enough to turn on.

For animation see www.falstad.com/circuit/e-multivib-a.html

Thermistor

- All resistors have temperature coefficient, usually considered bad.
- Bug becomes feature.

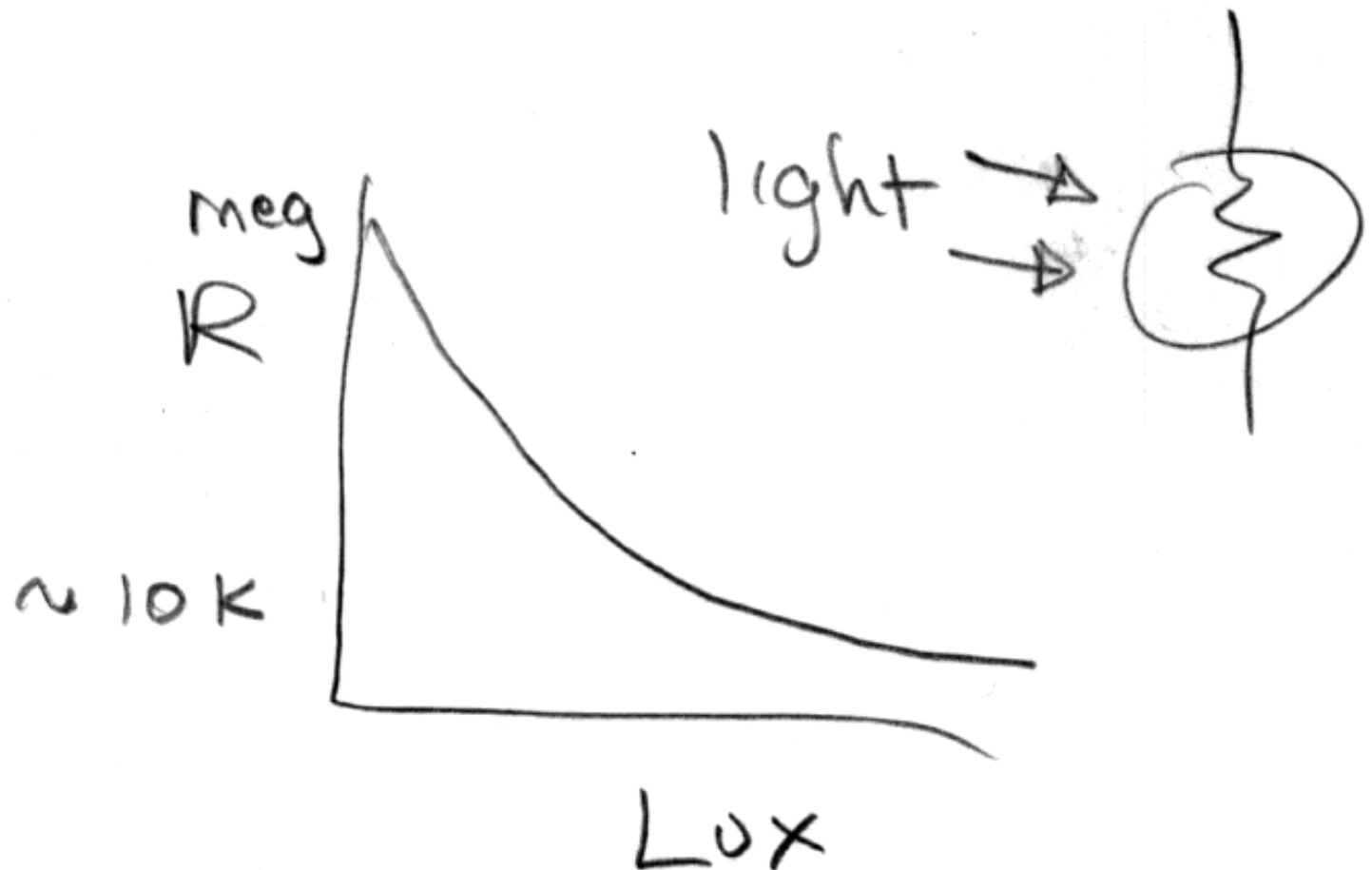


Photoresistor

- Cadmium sulfide between electrodes.
- Photons create free electrons.

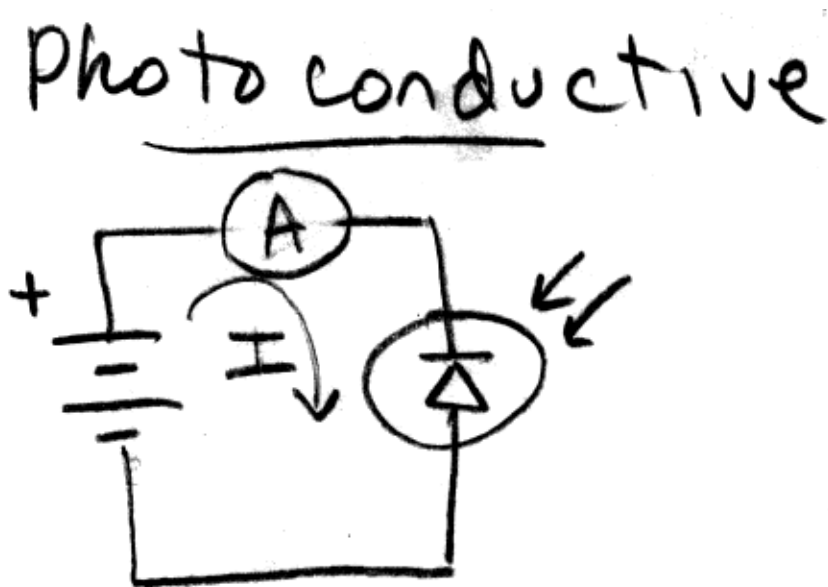


cheap
sturdy
slow
 $\sim 100 \text{ Hz}$



Photodiodes

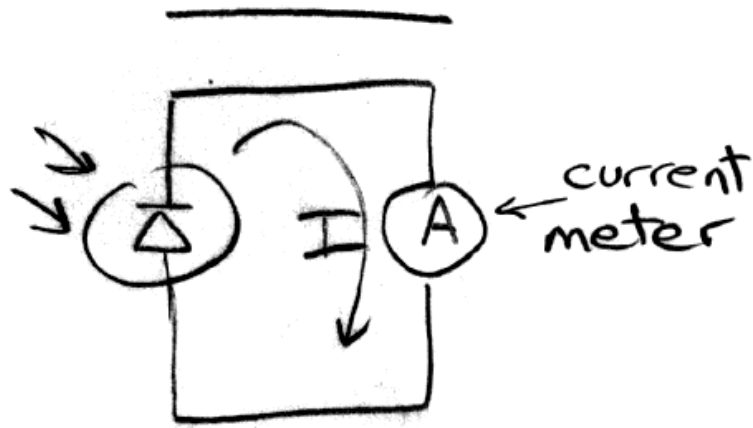
- Faster and more sensitive than photoresistors
- Two modes:
 - Photoconductive vs. Photovoltaic



strong signal
leakage current
("shot" noise)

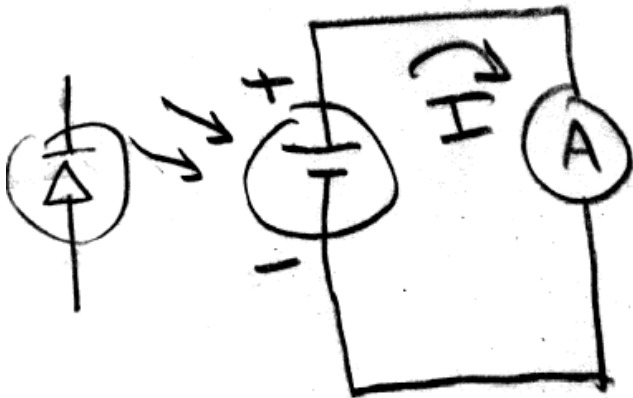
Photodiodes

Photovoltaic



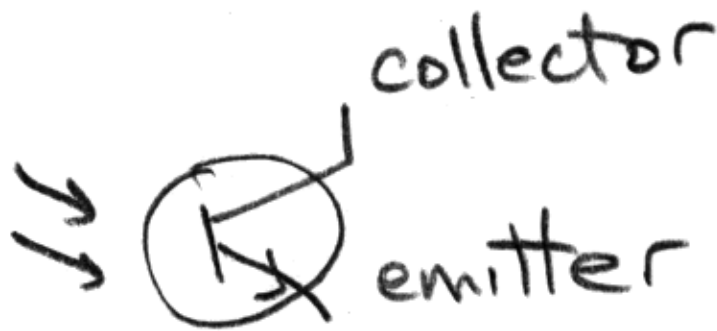
greatest sensitivity
(low noise)
but can be very
small currents

Solar cells - Photovoltaic with
large surface
area



Phototransistors

- Faster than photodiodes

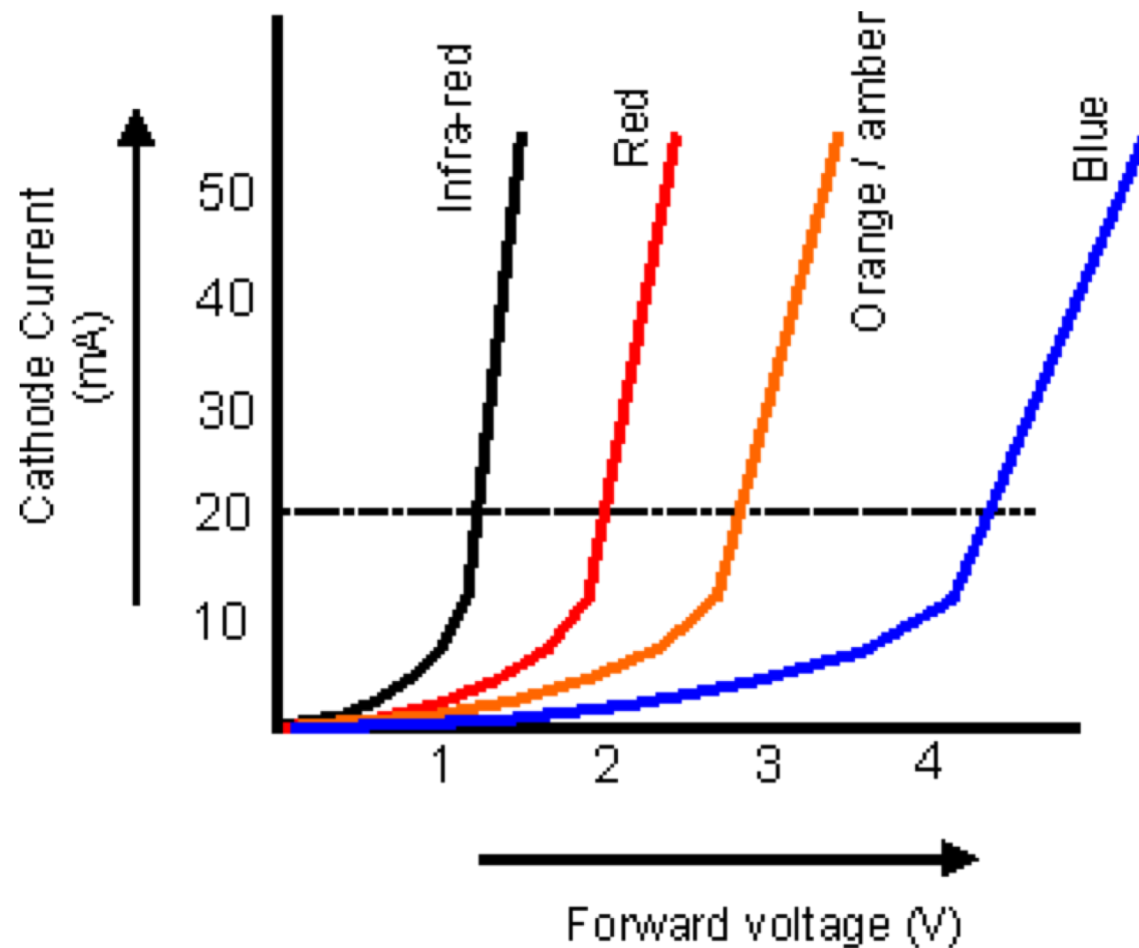
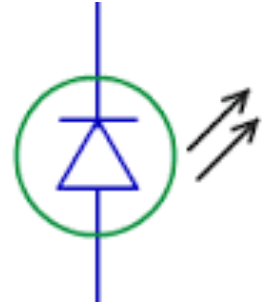


very sensitive

light generates the
base current

Light Emitting Diode (LED)

- Forward bias voltage is higher and varies with color since photon energy $E = h\nu$, where ν is frequency and h is Planck's constant.



Discovery of Infrared

- William Herschel 1800 with a prism and a thermometer
(also discovered Uranus)

